

Atty. Docket No.:
H0004037
(1139.1128101)

Serial No.:
10/620,512

LIST OF PATENTS AND PUBLICATIONS FOR
APPLICANT'S INFORMATION
DISCLOSURE STATEMENT

Applicant: Raymond W. Blasingame et al.

Filing Date:
July 16, 2003

Group Art:
unknown

U.S. PATENT DOCUMENTS

Examiner Initial	Document No.	Date	Name	Class	Sub Class	Filing Date If Appropriate
Aullab	US2001/0004414 A1	06/21/2001	Kuhn et al.			
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	4,660,207	04/21/1987	Svilans			
	4,675,058	06/23/1987	Plaster			
	4,784,722	11/15/1988	Liau et al.			
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	4,956,844	09/11/1990	Goodhue et al.			
	5,031,187	07/09/1991	Orenstein et al.			
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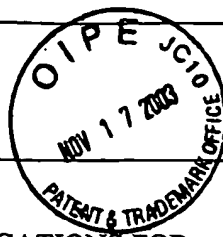
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<i>Aullab</i>	5,216,263	06/01/1993	Paoli			
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Alb	5,396,508	03/17/1995	Bour et al.			
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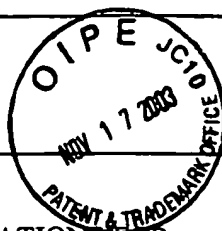
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<i>Autch</i>	5,606,572	02/25/1997	Swirhun et al.			
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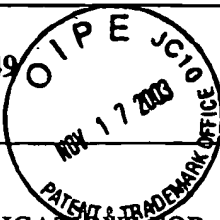
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<i>Handla</i>	5,892,784	04/06/1999	Tan et al.			
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	5,896,408	04/20/1999	Corzine et al.			
	5,901,166	05/04/1999	Nitta et al.			
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	5,908,408	06/1999	McGary et al.			
	5,936,266	08/10/1999	Holonyak, Jr. et al.			
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	5,953,362	09/14/1999	Pamulapati et al.			
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	6,002,705	12/14/1999	Thornton			
	6,008,675	12/28/1999	Handa			
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<i>Handla</i>	6,133,590	10/17/2000	Ashley et al.			



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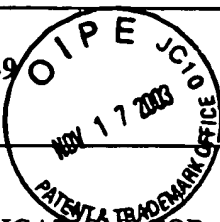
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<i>Sub 6</i>	6,144,682	11/07/2000	Sun			
	6,154,480	11/28/2000	Magnusson et al.			
	6,185,241	02/06/2001	Sun			
	6,191,890	02/20/2001	Baets et al.			
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	6,212,312	04/03/2001	Grann et al.			
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	6,302,596	10/16/2001	Cohen et al.			
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	6,455,879	09/24/2002	Ashley et al.			
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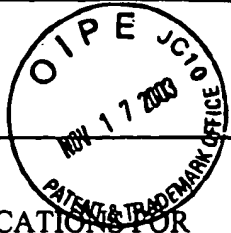
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<i>Julia</i>	6,487,231	11/26/2002	Boucart et al.			
	6,490,311	12/03/2002	Boucart et al.			
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	6,496,621	12/17/2002	Kathman et al.			
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	6,515,308	02/04/2003	Kneissl et al.			
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	6,542,531	04/01/2003	Sirbu et al.			
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Examiner Initial	Document No.	Date	Country	Translation Yes No
<i>Julia</i>	JP 60123084	01/07/1985	JP	Abstract
	EP 0288184 A2	10/26/1988	EP	
	JP 02054981	02/23/1990	JP	Abstract
	JP 5299779	11/12/1993	JP	Abstract
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	EP 0776076 A1	05/28/1997	EP	Abstract
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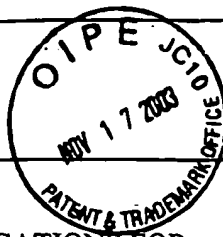
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Auk)	Banwell et al., "VCSE Laser Transmitters for Parallel Data Links", <u>IEEE Journal of Quantum Electronics</u> , Vol. 29, No. 2, February 1993, pp. 635-644.
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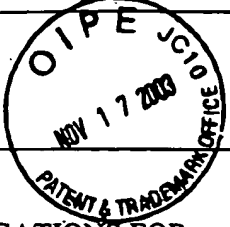
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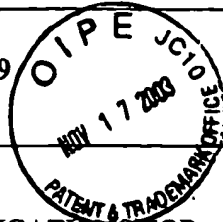


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EXAMINER: Akm E. Ullah	DATE CONSIDERED: 5/4/2005
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